

RGWS00TS65

650V 50A Field Stop Trench IGBT

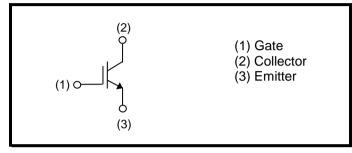
V _{CES}	650V
I _{C (100°C)}	50A
V _{CE(sat) (Typ.)}	1.6V
P_D	245W

Outline TO-247GE (1) (2)(3)

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

●Inner Circuit



Application

PFC

Solar converters

Mid to high switching frequency converters

Packaging Specifications

	3g - p	
	Packaging	Tube
	Reel Size (mm)	-
Typo	Tape Width (mm)	-
Type	Basic Ordering Unit (pcs)	600
	Packing Code	C13
	Marking	RGWS00TS65

● **Absolute Maximum Ratings** (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Collector Current	T _C = 25°C	I _C	88	Α
	T _C = 100°C	I _C	54	Α
Pulsed Collector Current		I _{CP} *1	150	А
Power Dissipation	$T_C = 25^{\circ}C$ P_D		245	W
	T _C = 100°C	P_{D}	121	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{imax}.

●Thermal Resistance

Doromotor	Symbol	Values			Linit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.61	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions		Linit		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	-	-	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	-	1	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V$, $V_{CE} = 0V$	ı	ı	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 26.0 \text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = 50A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.6 2.0	2.0	V

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Doromotor	Symbol	Conditions	Values			Linit
Parameter			Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	$V_{CE} = 30V$,	-	3320	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$,	-	83	-	pF
Reverse transfer Capacitance	C _{res}	f = 1MHz	-	60	-	
Total Gate Charge	Q_g	V _{CE} = 400V,	-	108	-	
Gate - Emitter Charge	Q_ge	$I_{\rm C} = 50A$,	-	22	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	42	-	
Turn - on Delay Time	t _{d(on)}		-	46	-	
Rise Time	t _r	$I_C = 50A, V_{CC} = 400V,$ $V_{GF} = 15V, R_G = 10\Omega,$	-	20	-	ns
Turn - off Delay Time	t _{d(off)}	$T_i = 25^{\circ}C$	-	145	-	
Fall Time	t _f	Inductive Load	-	38	-	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	0.98	-	
Turn - off Switching Loss	E _{off}	,	-	0.91	-	mJ
Turn - on Delay Time	t _{d(on)}		-	43	-	
Rise Time	t _r	I_C = 50A, V_{CC} = 400V, V_{GE} = 15V, R_G = 10 Ω , T_j = 175°C Inductive Load *E _{on} include diode reverse recovery	-	24	-	no
Turn - off Delay Time	t _{d(off)}		-	165	-	ns
Fall Time	t _f		-	78	-	
Turn - on Switching Loss	E _{on}		-	1.02	-	I
Turn - off Switching Loss	E_{off}		-	1.19	-	mJ
Reverse Bias Safe Operating Area	RBSOA	$I_C = 150A$, $V_{CC} = 520V$ $V_P = 650V$, $V_{GE} = 15V$ $R_G = 100\Omega$, $T_j = 175^{\circ}C$	FU	LL SQUA	RE	-

•Electrical Characteristic Curves

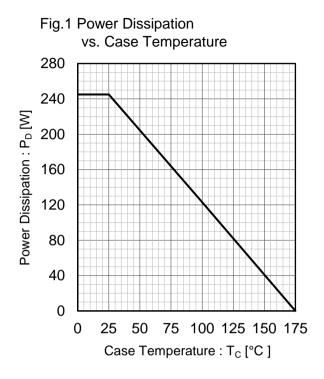


Fig.2 Collector Current vs. Case Temperature 100 80 Collector Current : Ic [A] 60 40 20 $T_i \le 175^{\circ}C$ _{GE} ≥ 15V 0 50 75 100 125 150 175 25 0 Case Temperature : T_C [°C]

Fig.3 Forward Bias Safe Operating Area

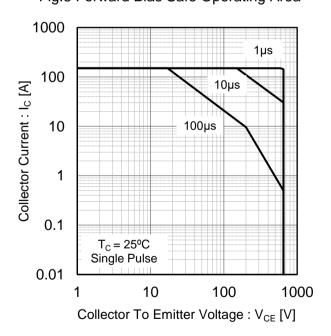
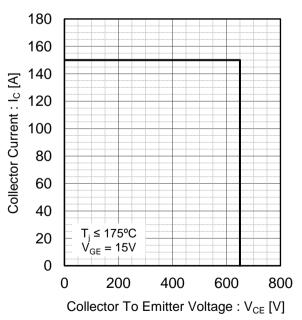


Fig.4 Reverse Bias Safe Operating Area



• Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

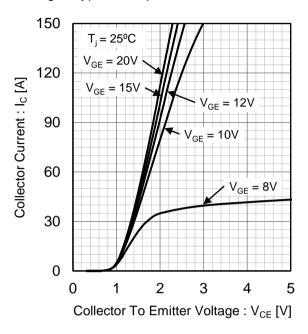


Fig.6 Typical Output Characteristics

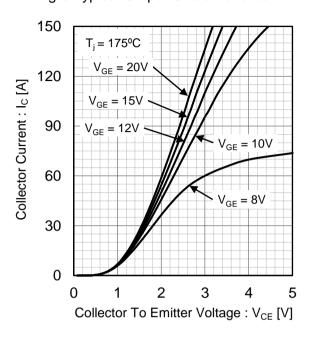


Fig.7 Typical Transfer Characteristics

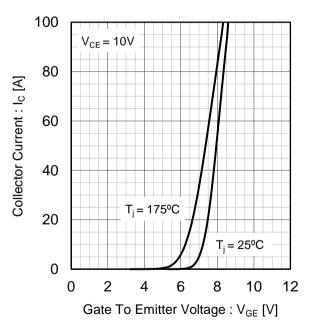
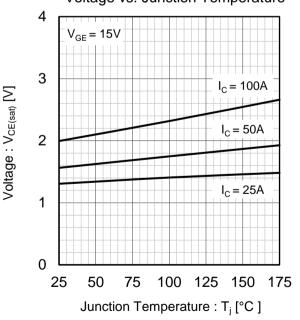


Fig.8 Typical Collector to Emitter Saturation Voltage vs. Junction Temperature



Collector To Emitter Saturation

• Electrical Characteristic Curves

Fig.9 Typical Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage

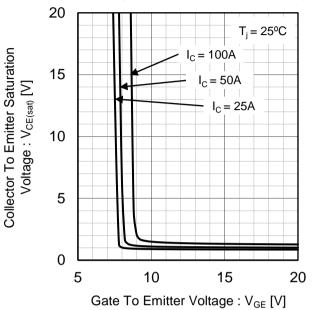


Fig.10 Typical Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage

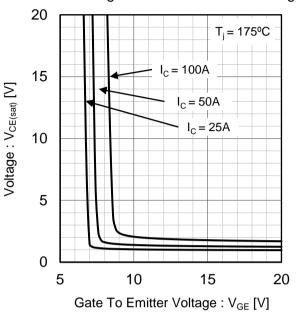


Fig.11 Typical Switching Time vs. Collector Current

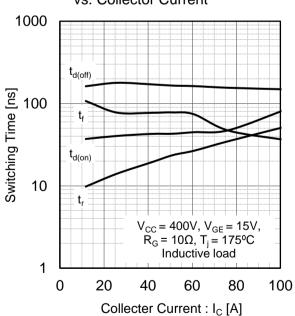
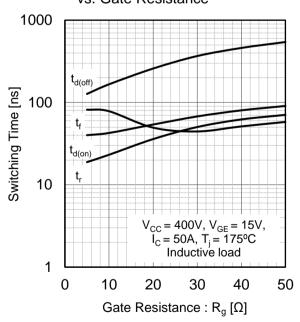


Fig.12 Typical Switching Time vs. Gate Resistance



Collector To Emitter Saturation

• Electrical Characteristic Curves

Fig.13 Typical Switching Energy Losses vs. Collector Current

10 E_{off} $V_{CC} = 400V, V_{GE} = 15V, R_{G} = 10\Omega, T_{J} = 175^{\circ}C$ Inductive load

0 20 40 60 80 100

Collecter Current : I_C [A]

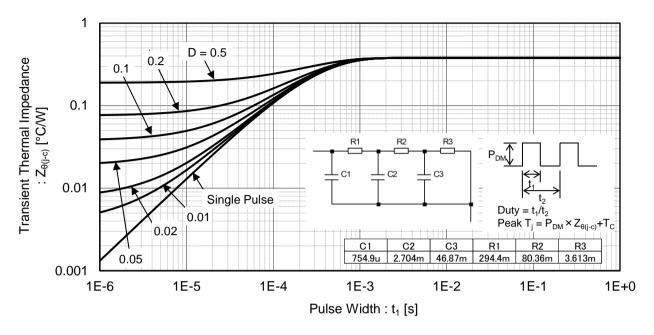
Fig.14 Typocal Switching Energy Losses vs. Gate Resistance 10 Switching Energy Losses [mJ] $\mathsf{E}_{\mathsf{off}}$ 1 E_{on} 0.1 V_{CC} = 400V, I_{C} = 50A, V_{GE} = 15V, T_{j} = 175°C Inductive load 0.01 20 0 10 30 40 50 Gate Resistance : $R_G[\Omega]$

Fig.15 Typical Capacitance vs. Collector to Emitter Voltage 10000 Cies 1000 Capacitance [pF] $\mathsf{C}_{\mathsf{oes}}$ 100 C_{res} 10 f = 1MHz $V_{GE} = 0V$ $T_i = 25^{\circ}C$ 1 0.01 0.1 1 10 100 Collector To Emitter Voltage: V_{CE} [V]

Fig.16 Typical Gate Charge 15 Gate To Emitter Voltage: VGE [V] 10 5 $V_{CC} = 400V$ $\widetilde{I_C} = 50A$ $T_i = 25^{\circ}C$ 0 0 20 40 60 80 100 120 Gate Charge: Qq [nC]

•Electrical Characteristic Curves

Fig.17 Typical IGBT Transient Thermal Impedance



●Inductive Load Switching Circuit and Waveform

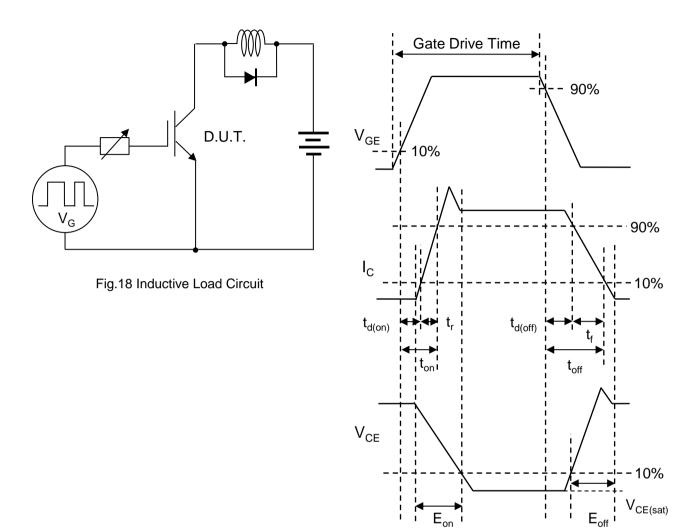


Fig.19 Inductive Load Waveform

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